

1200V, 40A, Trench FS II Fast IGBT

General Description

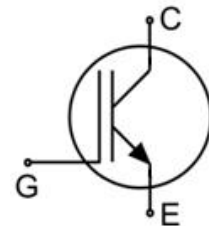
Using NCE's proprietary trench design and advanced FS (Field Stop) second generation technology, the 1200V Trench FSII IGBT offers superior conduction and switching performances, and easy parallel operation;

Features

- Trench FSII Technology Offering
- Very low $V_{CE(sat)}$
- High speed switching
- Positive temperature coefficient in $V_{CE(sat)}$
- Very tight parameter distribution
- High ruggedness, temperature stable behavior

Application

- PV power
- Three-level Solar String Inverter
- UPS



Schematic diagram

Package Marking and Ordering Information

Device	Device Package	Device Marking
NCE40T120VT	TO-247	NCE40T120VT



TO-247

Absolute Maximum Ratings ($T_c=25^{\circ}\text{C}$ unless otherwise noted)

Symbol	Parameter	Value	Units
V_{CES}	Collector-Emitter Voltage	1200	V
V_{GES}	Gate- Emitter Voltage	± 30	V
I_C	Collector Current	80	A
	Collector Current @ $T_C = 100^{\circ}\text{C}$	40	A
I_{Cpuls}	Pulsed Collector Current, t_p limited by T_{jmax}	160	A
-	turn off safe operating area, $V_{CE}=1200\text{V}$, $T_j=175^{\circ}\text{C}$	160	A
P_D	Power Dissipation @ $T_C = 25^{\circ}\text{C}$	468	W
	Power Dissipation @ $T_C = 100^{\circ}\text{C}$	234	W
T_J, T_{stg}	Operating Junction and Storage Temperature Range	-55 to +175	$^{\circ}\text{C}$
T_L	Maximum Temperature for Soldering	260	$^{\circ}\text{C}$

Thermal Characteristic

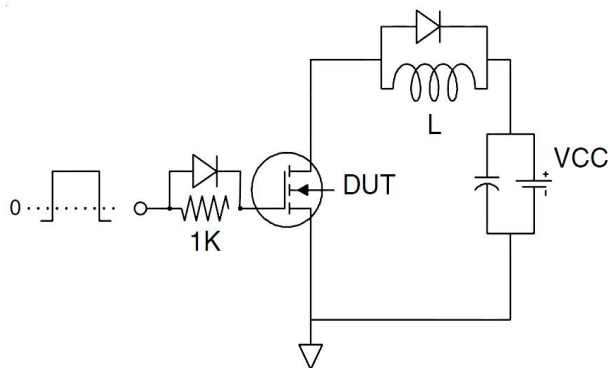
Symbol	Parameter	Value	Units
$R_{\theta JC}$	Thermal Resistance, Junction to case for IGBT	0.32	$^{\circ}\text{C/W}$
$R_{\theta JA}$	Thermal Resistance, Junction to Ambient	40	$^{\circ}\text{C/W}$

Electrical Characteristics ($T_c=25^{\circ}\text{C}$ unless otherwise noted)

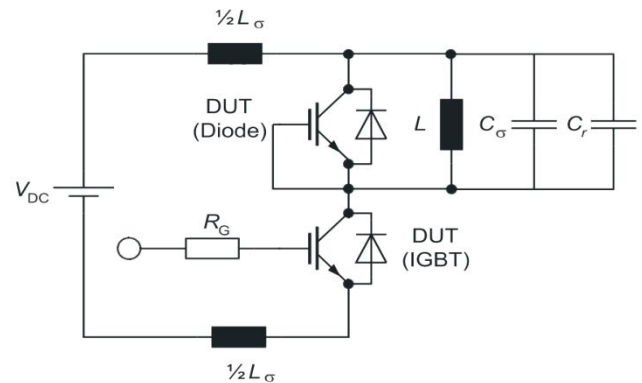
Symbol	Parameter	Conditions		Value			Units
				Min.	Typ.	Max.	
Static Characteristics							
V _{(BR)CES}	Collector-Emitter Breakdown Voltage	V _{GE} =0V, I _{CE} =1mA		1200	--	--	V
I _{CES}	Collector-Emitter Leakage Current	V _{GE} =0V, V _{CE} =1200V		--	--	200	uA
I _{GES(F)}	Gate to Emitter Forward Leakage	V _{GE} =+30V, V _{CE} =0V		--	--	200	nA
I _{GES(R)}	Gate to Emitter Reverse Leakage	V _{GE} =-30V, V _{CE} =0V		--	--	200	nA
V _{CE(sat)}	Collector-Emitter Saturation Voltage	I _C =40A,	T _J =25°C	--	1.70	1.95	V
		V _{GE} =15V	T _J =175°C	--	1.95	--	V
V _{GE(th)}	Gate Threshold Voltage	I _C =1mA, V _{CE} =V _{GE}		4.5	--	6.0	V
Dynamic Characteristics							
C _{ies}	Input Capacitance	V _{CE} =30V, V _{GE} =0V, f=1MHz		--	5590	--	pF
C _{oes}	Output Capacitance			--	177	--	
C _{res}	Reverse Transfer Capacitance			--	134	--	
Q _g	Total Gate Charge	V _{CC} =960V, I _C =40A, V _{GE} =15V		--	298	--	nC
Q _{ge}	Gate to Emitter Charge			--	52	--	
Q _{gc}	Gate to Collector Charge			--	169	--	
Switching Characteristics							
t _{d(ON)}	Turn-on Delay Time	V _{CE} =600V, I _C =40A, V _{GE} =0/15V, R _g =8Ω, Inductive Load		--	19	--	ns
t _r	Rise Time			--	17	--	
t _{d(OFF)}	Turn-Off Delay Time			--	170	--	
t _f	Fall Time			--	18	--	
E _{on}	Turn-On Switching Loss			--	2.2	--	mJ
E _{off}	Turn-Off Switching Loss			--	1.3	--	
E _{ts}	Total Switching Loss			--	3.5	--	
E _{on}	Turn-On Switching Loss	V _{CE} =600V, I _C =40A,		--	2.8	--	mJ
E _{off}	Turn-Off Switching Loss	V _{GE} =0/15V, R _g =8Ω,		--	1.6	--	
E _{ts}	Total Switching Loss	T _J =175°C		--	4.4	--	

Test Circuit

1) Gate Charge Test Circuit

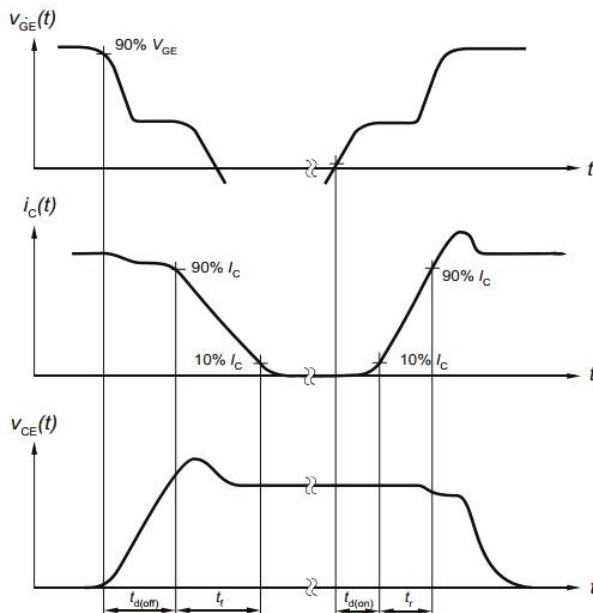


2) Switch Time Test Circuit

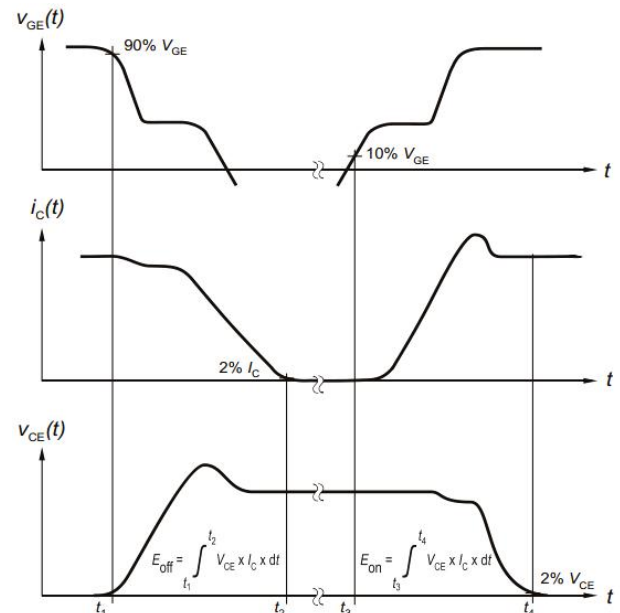


Switching characteristics

1) Definition of switching times



2) Definition of switching losses



Typical Electrical and Thermal Characteristics

Figure 1 Output Characteristics

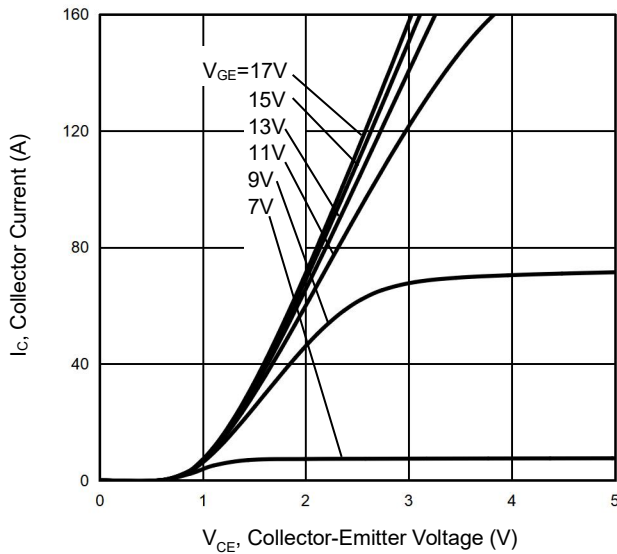


Figure 2 Transfer Characteristics

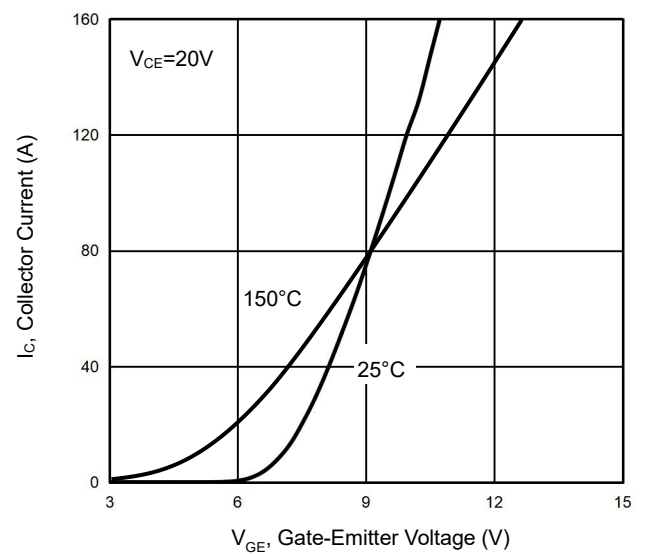


Figure 3 $V_{CE(sat)}$ vs. Case Temperature

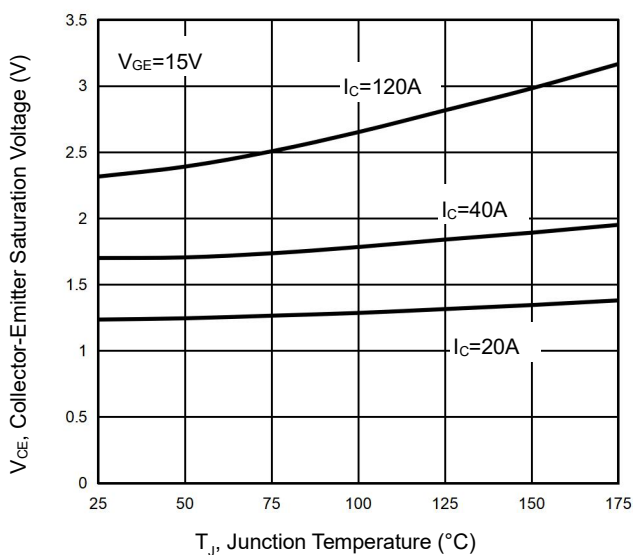


Figure 4 Saturation Voltage vs. V_{GE}

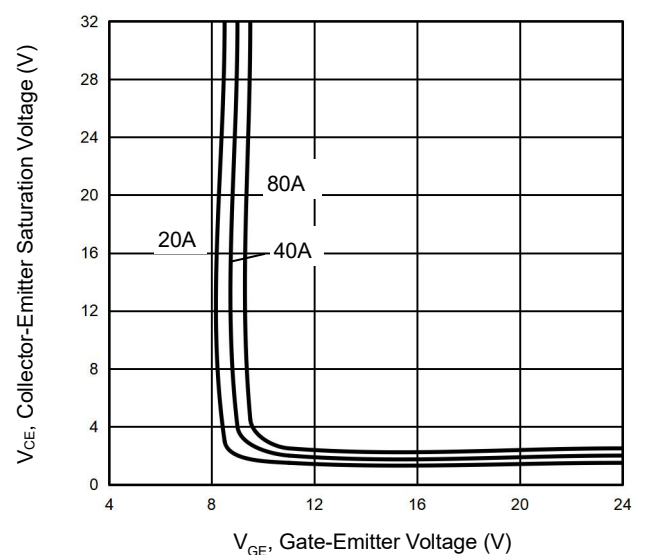


Figure 5 Capacitance Characteristics

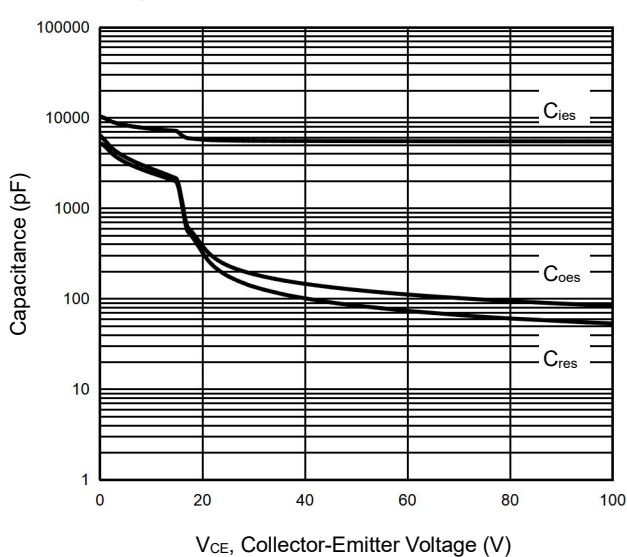
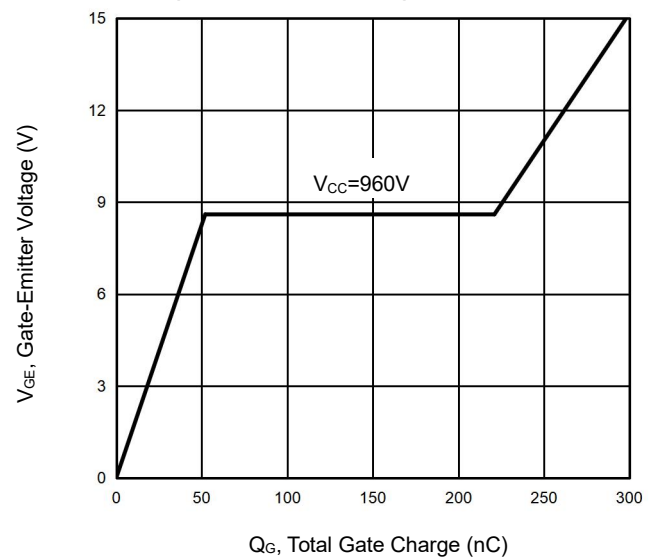


Figure 6 Gate Charge Wave Form



Typical Electrical and Thermal Characteristics

Figure 7 Switching Loss vs. R_G

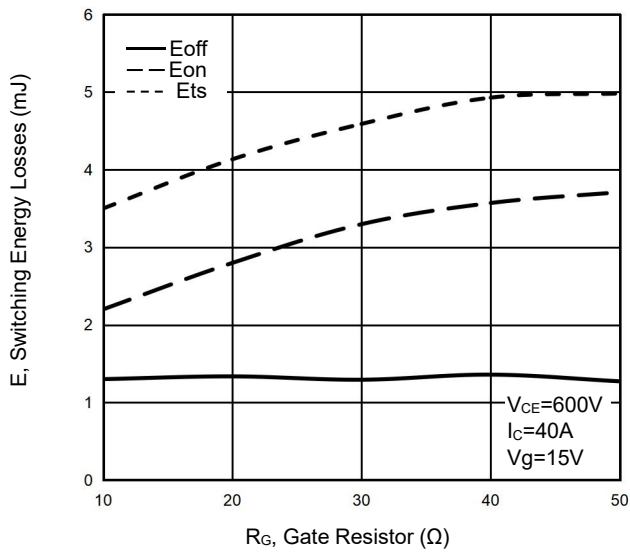


Figure 8 Switching Loss vs. Collector Current

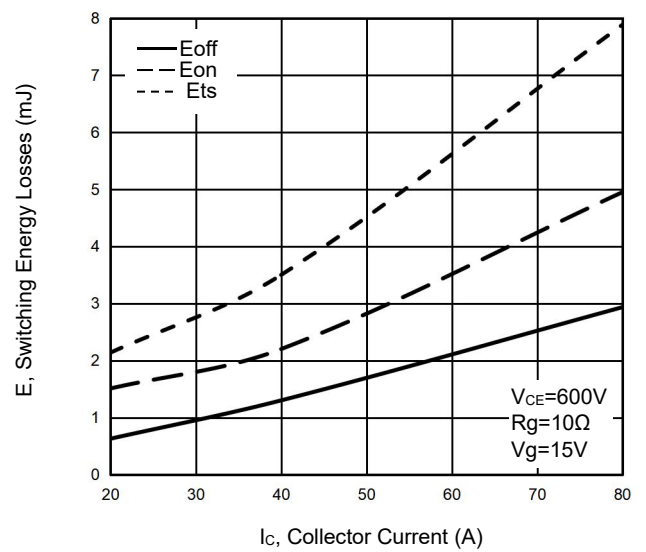


Figure 9 Switching Loss vs. Collector Current

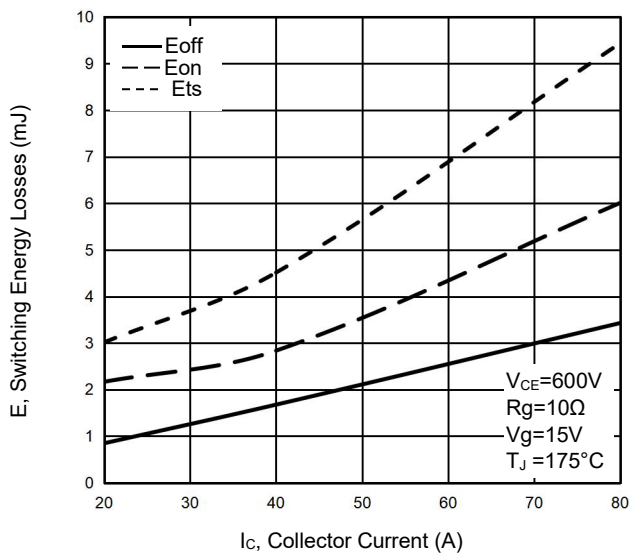


Figure 10 P_{tot} vs. Case Temperature

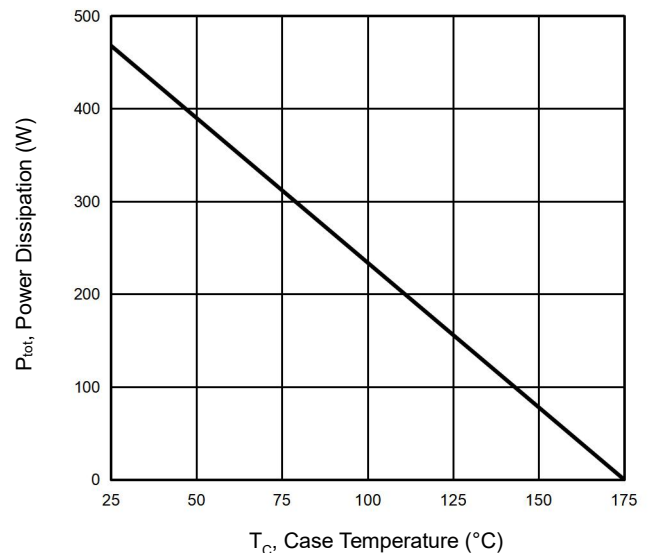


Figure 11 V_{CES} vs. Temperature

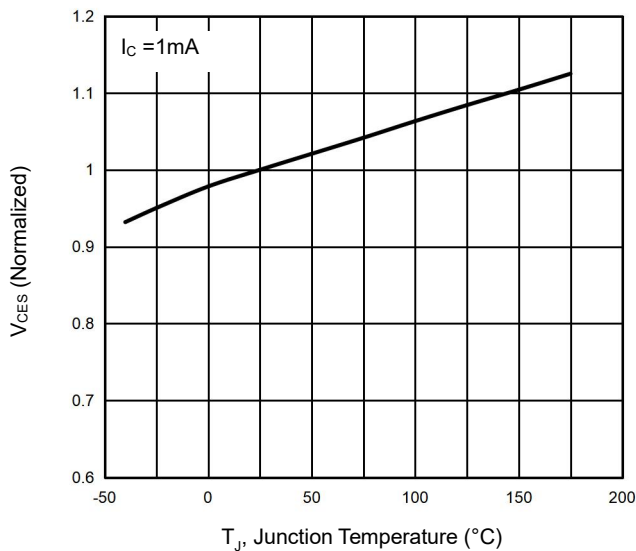
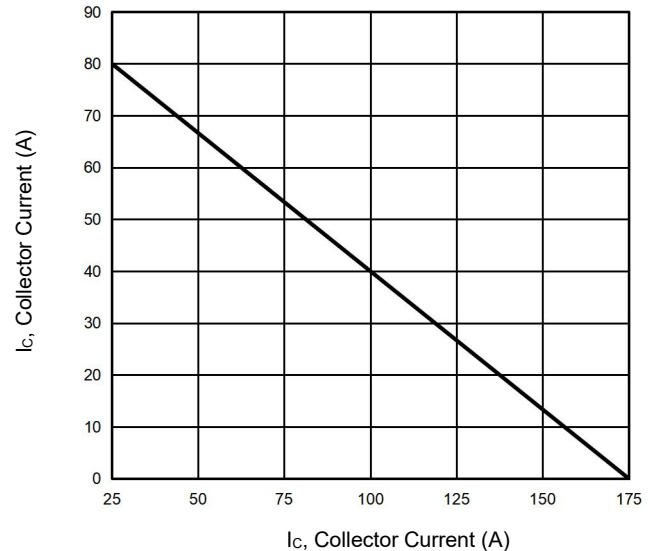


Figure 12 I_C vs. Temperature



Typical Electrical and Thermal Characteristics

Figure 13 Switching Energy vs. Temperature

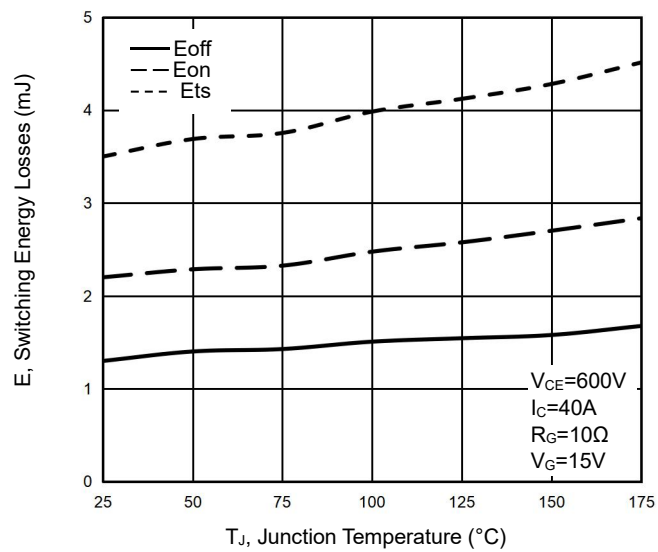
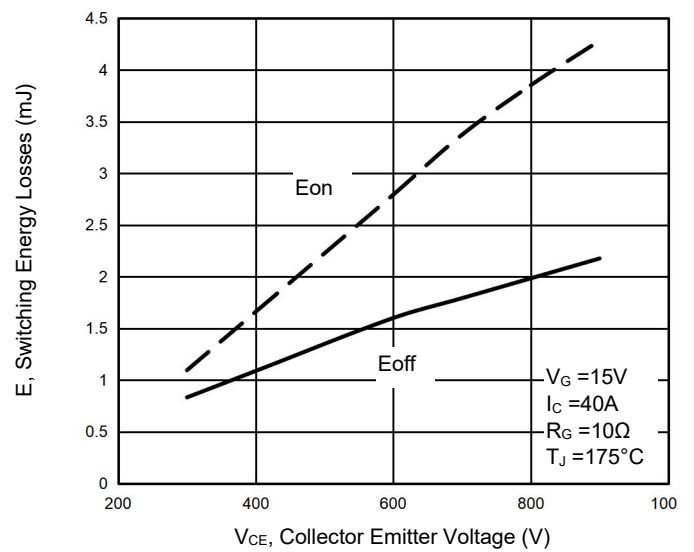
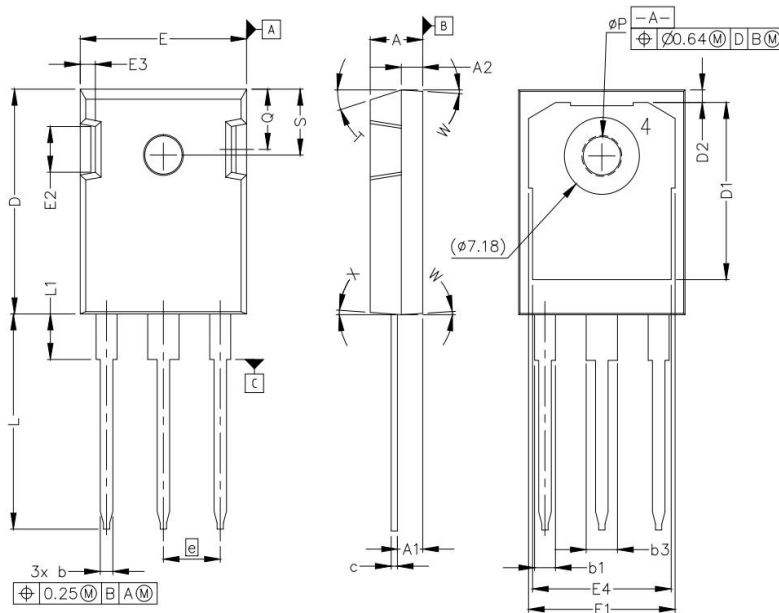


Figure 14 Switching Loss vs. V_{CE}

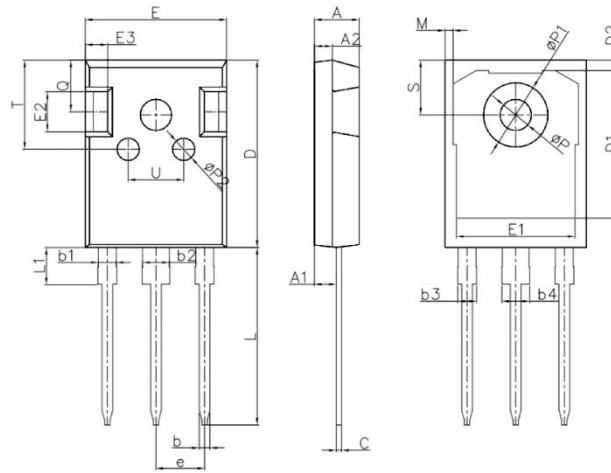


TO-247-B Package Information



Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min.	Max.	Min.	Max.
A	4.83	5.21	0.19	0.21
A1	2.29	2.54	0.09	0.10
A2	1.91	2.16	0.08	0.09
b	1.07	1.33	0.04	0.05
b1	1.91	2.41	0.08	0.10
b3	2.87	3.38	0.11	0.13
c	0.55	0.68	0.02	0.03
D	20.80	21.10	0.82	0.83
D1	16.25	17.65	0.64	0.70
D2	0.95	1.25	0.04	0.05
E	15.75	16.13	0.62	0.64
E1	13.10	14.15	0.52	0.56
E2	3.68	5.10	0.15	0.20
E3	1.00	1.90	0.04	0.08
E4	12.38	13.43	0.49	0.53
e	5.44 BSC		0.21 BSC	
L	19.81	20.32	0.78	0.80
L1	4.10	4.40	0.16	0.17
ØP	3.51	3.65	0.14	0.15
Q	5.49	6.00	0.22	0.24
S	6.04	6.30	0.24	0.25
T	17.5° REF			
W	3.5° REF			
X	4° REF			

TO-247-E Package Information



Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min.	Max.	Min.	Max.
A	4.90	5.10	0.19	0.20
A1	2.31	2.51	0.09	0.10
A2	1.90	2.10	0.07	0.08
b	1.16	1.26	0.05	0.06
b1	1.96	2.06	0.08	0.09
b2	2.96	3.06	0.12	0.13
b3	--	2.25	--	0.09
b4	--	3.25	--	0.13
c	0.59	0.66	0.02	0.03
D	20.90	21.10	0.82	0.83
D1	16.25	16.85	0.64	0.66
D2	1.05	1.35	0.04	0.05
E	15.70	15.90	0.62	0.63
E1	13.10	13.50	0.52	0.53
E2	4.40	4.60	0.17	0.18
E3	2.40	2.60	0.09	0.10
e	5.436 BSC		0.214 BSC	
L	19.80	20.10	0.78	0.79
L1	--	4.30	--	0.17
M	0.35	0.95	0.01	0.04
P	3.40	3.60	0.13	0.14
P1	7.00	7.40	0.28	0.29
P2	2.40	2.60	0.09	0.10
Q	5.60	6.00	0.22	0.24
S	6.05	6.25	0.24	0.25
T	9.80	10.20	0.39	0.40
U	6.00	6.40	0.24	0.25

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